

AOZ8831-05

Ultra Low Capacitance One-line Bi-directional TVS Diode

General Description

The AOZ8831-05 is an ultra low capacitance one-line bi-directional transient voltage suppressor diode designed to protect high speed data lines and voltage sensitive electronics from high transient conditions and ESD.

This device incorporates one TVS diode in an ultra-small DFN 1.0 x 0.6 package. It may be used to meet the ESD immunity requirements of IEC 61000-4-2, Level 4.

The AOZ8831-05 comes in an RoHS compliant DFN package and is rated over a -40°C to +85°C ambient temperature range.

The ultra-small $1.0 \times 0.6 \times 0.4$ mm DFN package makes it ideal for applications where PCB space is a premium. The small size and high ESD protection makes it ideal for protecting voltage sensitive electronics from high transient conditions and ESD.

Features

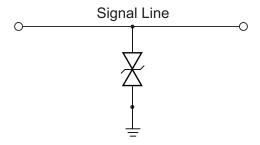
- ESD protection for high-speed data lines:
 - Exceeds: IEC 61000-4-2 (ESD) ±20kV (air), ±20kV (contact)
 - Human Body Model (HBM) ±15kV
- Small package saves board space
- Ultra low capacitance: 0.22pF
- Low clamping voltage
- Operating voltage: 5V
- Pb-free device

Applications

- Portable handheld devices
- Notebook computers
- Digital Cameras
- Portable GPS



Typical Application



Bidirection Protection of Single Line

Pin Configuration





Ordering Information

Part Number	Ambient Temperature Range	Package	Environmental		
AOZ8831DT-05	-40°C to +85°C	DFN 1.0 x 0.6	Green Product		



AOS Green Products use reduced levels of Halogens, and are also RoHS compliant. Please visit www.aosmd.com/media/AOSGreenPolicy.pdf for additional information.

Absolute Maximum Ratings

Exceeding the Absolute Maximum ratings may damage the device.

Parameter	Rating				
VP – VN	5.5V				
Peak Pulse Current (I_{PP}), $t_P = 8/20 \mu s$	6A				
Peak Pulse Power (IEC61000-4-5 8/20µs current pulse)	90W				
Storage Temperature (T _S)	-65°C to +150°C				
ESD Rating per IEC61000-4-2, Contact ⁽¹⁾	±20kV				
ESD Rating per IEC61000-4-2, Air ⁽¹⁾	±20kV				
ESD Rating per Human Body Model ⁽²⁾	±15kV				

Notes:

- 1. IEC 61000-4-2 discharge with C_Discharge = 150pF, R_Discharge = 330 Ω .
- 2. Human Body Discharge per MIL-STD-883, Method 3015 $C_{Discharge}$ = 100pF, $R_{Discharge}$ = 1.5k Ω .

Maximum Operating Ratings

Parameter	Rating
Junction Temperature (T _J)	-40°C to +125°C



Electrical Characteristics

 $T_A = 25$ °C unless otherwise specified.

Symbol	Parameter	Diagram
I _{PP}	Maximum Reverse Peak Pulse Current ⁽³⁾ (IEC61000-4-5 8/20µs pulse)	I †
V _{CL}	Clamping Voltage @ I _{PP} ⁽³⁾	IPP
V_{RWM}	Working Peak Reverse Voltage	
I _R	Maximum Reverse Leakage Current	V _{CL} V _{BR} V _{RWM} V
V _{BR}	Breakdown Voltage	IR VRWM VBR VCL
СЈ	Capacitance @ V _R = 0 and f = 1MHz	

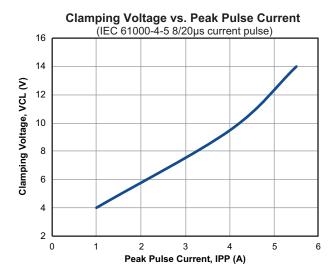
	Device	V _{RWM} (V)	V _{BR}	V _{BR} (V)		V _{CL} Max.			C _J (pF)		
Device	Marking	Max.	Min.	Max.	I _R (μΑ) Max.	I _{PP} = 1 A	I _{PP} = 4 A	I _{PP} = 6 A	Тур.	Max.	
AOZ8831DT-05	5	5.5	6	10	0.1	4	9.5	15	0.22	0.35	

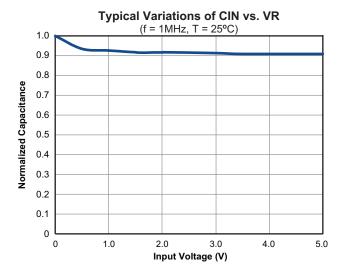
Notes:

3. These specifications are guaranteed by design and characterization.



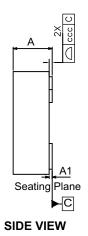
Performance Characteristics

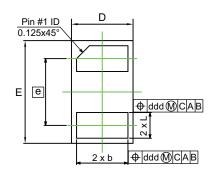






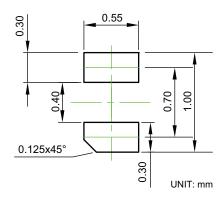
Package Dimensions, DFN 1.0 x 0.6





BOTTOM VIEW

RECOMMENDED LAND PATTERN



Dimensions in millimeters

Symbols	Min.	Nom.	Max.					
Α	0.31	0.38	0.40					
A1	0.00	0.02	0.05					
b	0.45	0.50	0.55					
D	0.55	0.60	0.65					
E	0.95	1.00	1.05		Г			
е	(0.95 1.00 1.05 0.65 BSC						
L	0.20	0.25	0.30					
CCC	0.03							
ddd	0.31 0.38 0.40 0.00 0.02 0.05 0.45 0.50 0.55 0.55 0.60 0.65 0.95 1.00 1.05 0.65 BSC 0.20 0.25 0.30							

Dimensions in inches

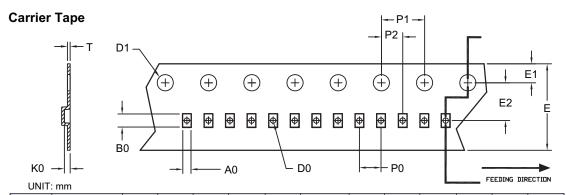
Symbols	Min.	Nom.	Max.				
Α	0.012	0.015	0.016				
A1	0.000	0.001	0.002				
b	0.018	0.020	0.022				
D	0.022	0.024	0.026				
E	0.037	0.039	0.041				
е	0.026 BSC						
L	0.008	0.010	0.012				
CCC	0.001						
ddd	0.004						

Notes:

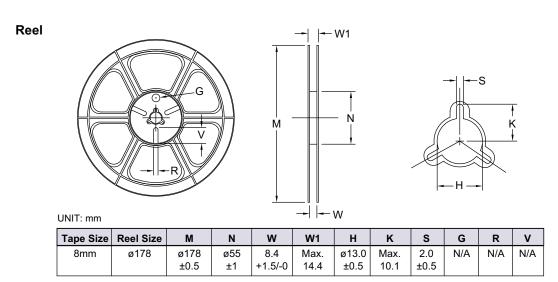
- 1. All dimensions are in millimeters, angles are in degrees.
- 2. Coplanarity applies to the exposed heat sink slug as well as the terminals.

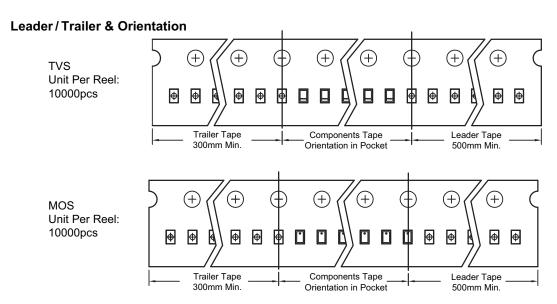


Tape and Reel Dimensions, DFN 1.0 x 0.6



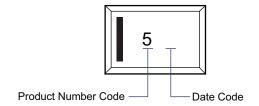
Option	Package	A0	В0	K0	D0	D1	E	E1	E2	P0	P1	P2	Т
А	DFN 1.0x0.6/ DFN 1.0x0.6A (8 mm)	0.69 ±0.05	1.19 ±0.05	0.66 ±0.05	0.40 ±0.05	1.50 ±0.10	8.00 +0.3/-0.1	1.75 ±0.10	3.50 ±0.05	2.00 ±0.05	4.00 ±0.10	2.00 ±0.05	0.23 ±0.02
В	DFN 1.0x0.6/ DFN 1.0x0.6A (8 mm)	0.65 ±0.04	1.05 ±0.04	0.61 ±0.04	0.40 ±0.05	1.50 ±0.10	8.00 +0.3/-0.1	1.75 ±0.10	3.50 ±0.05	2.00 ±0.10	4.00 ±0.10	2.00 ±0.05	0.20 ±0.05







Part Marking



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